

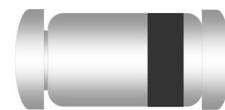


SEMICONDUCTOR

## 500 mW LL-34 Hermetically Sealed Glass Fast Switching Diodes


 SURFACE MOUNT  
 LL34

DEVICE MARKING DIAGRAM



Cathode Band Color : Black

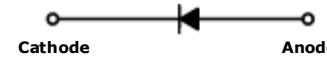
**Absolute Maximum Ratings**  $T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Value	Units
$P_D$	Power Dissipation	500	mW
$T_{STG}$	Storage Temperature Range	-65 to +150	°C
$T_J$	Operating Junction Temperature	+150	°C
$W_V$	Working Inverse Voltage	75	V
$I_o$	Average Rectified Current	150	mA
$I_{FM}$	Non-repetitive Peak Forward Current	450	mA
$I_{FSURGE}$	Peak Forward Surge Current (Pulse Width = 1.0 μsecond)	2	A

These ratings are limiting values above which the serviceability of the diode may be impaired.

### Specification Features:

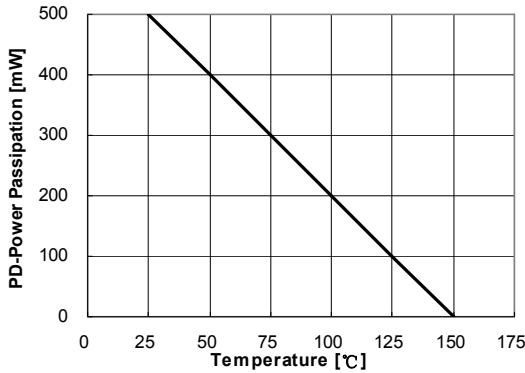
- Fast Switching Device ( $T_{RR} < 4.0 \text{ nS}$ )
- LL-34 (Mini-MELF) Package
- Surface Device Type Mounting
- Hermetically Sealed Glass
- Compression Bonded Construction
- All External Surfaces Are Corrosion Resistant And Terminals Are Readily Solderable
- RoHS Compliant
- Matte Tin (Sn) Terminal Finish
- Color band Indicates Negative Polarity



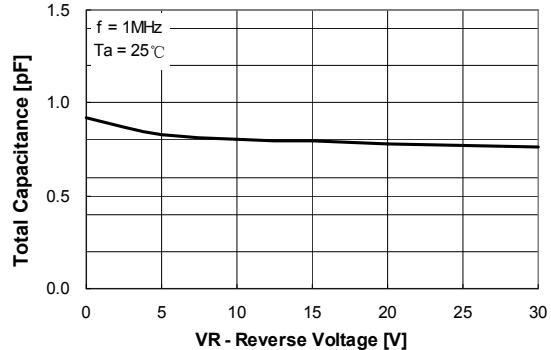
ELECTRICAL SYMBOL

**Electrical Characteristics**  $T_A = 25^\circ\text{C}$  unless otherwise noted

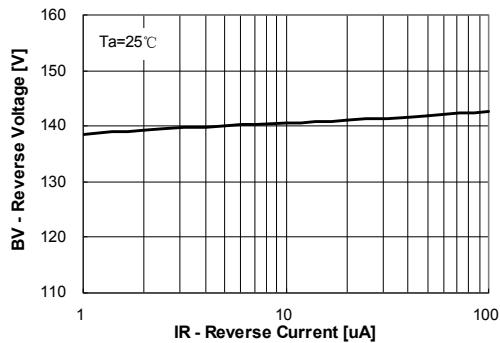
Symbol	Parameter	Test Condition	Limits		Unit
			Min	Max	
$B_V$	Breakdown Voltage	$I_R=100\mu\text{A}$ $I_R=5\mu\text{A}$	100 75		Volts
$I_R$	Reverse Leakage Current	$V_R=20\text{V}$ $V_R=75\text{V}$		25 5	nA μA
$V_F$	Forward Voltage TCLL4448, TCL914B TCLL4148 TCLL4448, TCL914B	$I_F=5\text{mA}$ $I_F=10\text{mA}$ $I_F=100\text{mA}$	0.62 1.0 1.0	0.72	Volts
$T_{RR}$	Reverse Recovery Time	$I_F=10\text{mA}, V_R=6\text{V}$ $R_L=100\Omega$ $I_{RR}=1\text{mA}$		4	nS
$C$	Capacitance	$V_R=0\text{V}, f=1\text{MHz}$		4	pF

**Typical Characteristics**


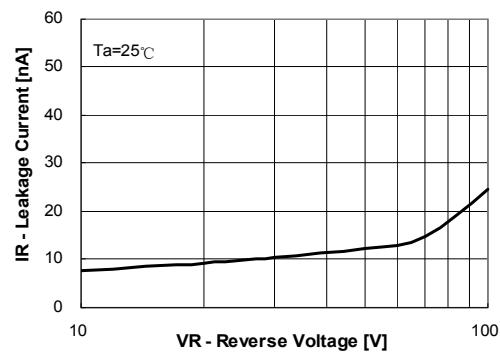
**Figure 1. Power Dissipation vs Ambient Temperature**  
Valid provided leads at a distance of 0.8mm from case are kept at ambient temperature



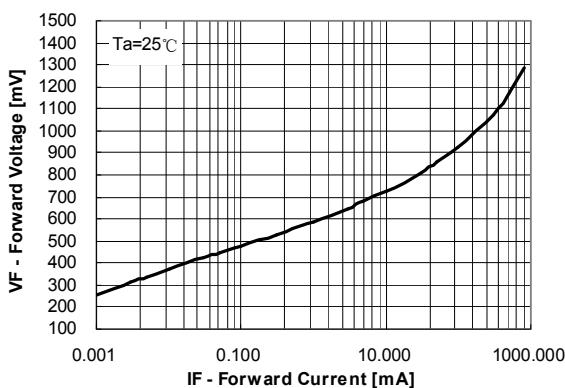
**Figure 2. Total Capacitance**



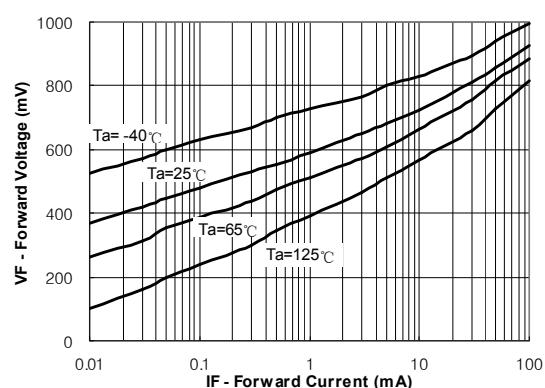
**Figure 3. Reverse Voltage vs Reverse Current**  
BV – 1.0uA to 100uA



**Figure 4. Reverse Current vs Reverse Voltage**  
IR – 10V to 100V



**Figure 5. Forward Voltage vs Forward Current**  
VF – 0.001mA to 800mA



**Figure 6. Forward Voltage vs Ambient Temperature**  
VF – 0.01mA to 100mA (-40 to +125 Deg C)



SEMICONDUCTOR

### Package Outline

Package	Case Outline				
LL34	DIM	LL-34			
		Millimeters		Inches	
		Min	Max	Min	Max
		A	3.30	0.130	0.142
		B	1.40	0.055	0.059
		C	0.35	0.014	0.020

Notes:

1. All dimensions are within DO213AC JEDEC standard.
2. LL-34 polarity denoted by cathode band.